

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
1	BRS	L1	1272	bipolar and substrate and semiconductor and (insulat\$4 near film) and pad\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/01/04 09:18			
2	BRS	L2	843	(bipolar near transistor) and substrate and semiconductor and (insulat\$4 near film) and pad\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/01/04 09:19			
3	BRS	L3	599	2 and capacit\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/01/04 09:34			
4	BRS	L4	9	(capacit\$4 near adjust\$4) and 3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/01/04 10:46			
5	BRS	L5	55	(capacit\$4 near adjust\$4) and substrate and semiconductor and (insulat\$4 near film) and pad\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/01/04 10:47			